

Efficient Knock-In by Genome Editing

BioDynamics Laboratory Inc.

Long single strand DNA (LsODN) Preparation Kit

For more information: http://www.funakoshi.co.jp/exports contents/80479

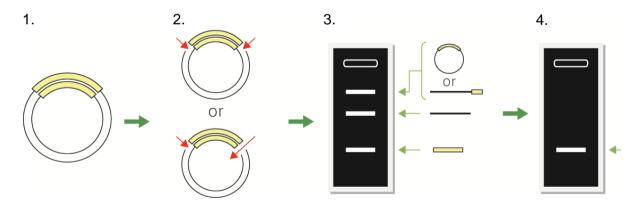
The Long ssDNA (LsODN) Preparation Kits provide a simple and easy method for generating a long ssDNA (<1,5 kb or < 3,0 kb).

Features

- A long ssDNA has a defined sequence and length.
- Simple principle and easy procedure.
- High yield and high quality.
- Best for effective knock-in by genome editing.

Principle

- 1. The DNA of interest is cloned into a plasmid using a pair of two nicking endonuclease sites or a combination of a nicking endonuclease site and a restriction enzyme site.
- 2. The resulting plasmid harboring the DNA is digested with a pair of two nicking endonucleases or a combination of a nicking endonuclease and a restriction enzyme.
- 3. The nicked plasmid is denatured and then subjected to agarose gel electrophoresis.
- 4. The band corresponding to a long ssDNA is excised and extracted.



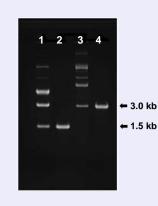
X Nicking endonuclease is not contained in this kit.

Kit Contents

Long ssDNA Preparation Kit					
for 1.5 kb	for 3.0 kb				
(#DS610)	(#DS620)				
pLSODN-1 Plasmid 10 μg (0.5 μg/μl)	pLSODN-3 Plasmid 10 μg (0.5 μg/μl)				
pLSODN-2D Plasmid 10 μg (0.5 μg/μl)	pLSODN-4D Plasmid 10 μg (0.5 μg/μl)				
Denaturing Gel-Loading Buffer 1 ml (100 loadings)					
DynaMarker [®] Prestain Marker for RNA High 90 μl (18 loadings) *					

^{*} Prestain Marker for RNA High is available separately.

Example Data



Lane 1: The double nicked pLSODN-1 harboring 1.5 kb DNA fragment

Lane 2: Purified long ssDNA (1.5 kb)

Lane 3: The double nicked pLSODN-3 harboring 3.0 kb DNA fragment

Lane 4: Purified long ssDNA (3.0 kb)

Figure: Long ssDNAs prepared by using this kit

A 1.5 kb DNA fragment of interest was cloned between the Nt.BspQI and the Nb.BsrDI sites of pLSODN-1.

Similarly, a 3.0 kb DNA fragment of interest was cloned between the Nt.BspQl and the Nb.BsrDl sites of pLSODN-3.

The plasmids were digested with Nt.BspQI and Nb.BsrD.

The double nicked plasmids were mixed with Denaturing Gel-loading Buffer and heated, then loaded to conventional non-denaturing agarose gel electrophoresis.

The band corresponding to a long ssDNA was excised and extracted.

Citation

ssODN-mediated knock-in with CRISPR-Cas for large genomic regions in zygotes.

Yoshimi K, Kunihiro Y, Kaneko T, Nagahora H, Voigt B, Mashimo T. *Nature Communications*. Jan; 20; 7:10431. (2016)

PMID: 26786405



nature.com » journal home » archive by date » january » full text
NATURE COMMUNICATIONS | ARTICLE OPEN

ssODN-mediated knock-in with CRISPR-Cas for large genomic regions in zygotes

Kazuto Yoshimi, Yayoi Kunihiro, Takehito Kaneko, Hitoshi Nagahora, Birger Voigt & Tomoji Mashimo

Product Information

[Manufacturer : BDL]

Product Name	Code	Size	Storage
Long ssDNA Preparation Kit for 1.5 kb	DS610	1 kit	-80℃
Long ssDNA Preparation Kit for 3.0 kb	DS620	1 kit	-80℃

■ Related Products

[Manufacturer : BDL]

Product Name	Code	Size	Storage
DynaMarker, Prestain Marker for RNA High	DM260S	90 µl	-80℃
	DM260	180 µl	-80℃

Check it out!

For gel excision, our "Gel Pipette" and "Funa-Gel Tip" are recommended.

For details:

Gel Pipette

http://www.funakoshi.co.jp/exports_contents/80506

Funa-Gel Tip

http://www.funakoshi.co.jp/exports_contents/80485







NOTE

All products here are research use only, not for diagnostic use.
 Specs might be changed for improvement without notice.

Numbers after "#" represents product code.

Company name and product name are trademark or registered mark.Please contact your local distributors for orders, quote request and inquiry.

Your Local Distributor



Bio-REV Pte. Ltd.

36 Toh Guan Road East, #01-39 Enterprise Hub, Singapore 608 580

Tel: (65) 6273-3022 Fax: (65) 6273-3020 Email: sales@bio-rev.com

Technical Support: techserv@bio-rev.com

Funakoshi Co., Ltd.

Address: 9-7 Hongo 2-Chome, Bunkyo-ku,

Tokyo 113-0033 JAPAN
Phone: +81-3-5684-6296
Fax: +81-3-5684-6297
Email: export@funakoshi.co.jp

ZF-Z04T-03 (2016.04)